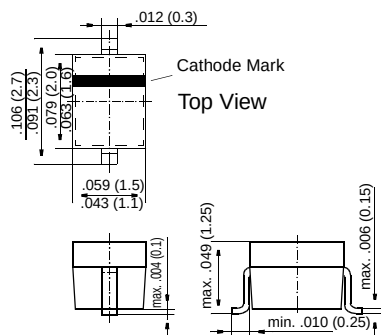


BB729S

Tuner Diodes

SOD-323



Dimensions in inches and (millimeters)

FEATURES

- ◆ Silicon epitaxial planar capacitance diodes with very wide effective capacitance variation for tuning the whole range of VHF CTV tuners. 
- ◆ These diodes are available as singles or as matched sets of two or more units according to the tracking condition described in the table of characteristics.
- ◆ This diode is also available in SOD-123 case with the type designation BB729.

MECHANICAL DATA

Case: SOD-323 Plastic Package

Weight: approx. 0.004 g

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified

	Symbol	Value	Unit
Reverse Voltage	V_R	32	V
Ambient Temperature	T_{amb}	125	°C
Storage Temperature Range	T_S	-55 to +125	°C

BB729S

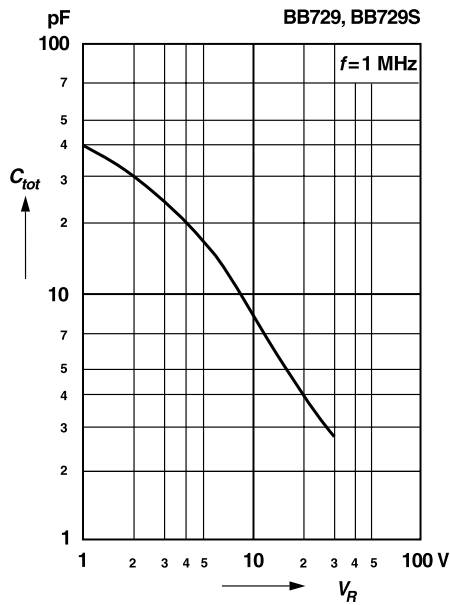
ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified

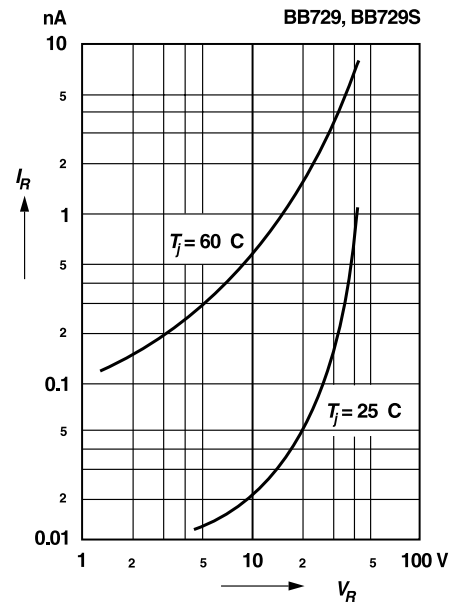
	Symbol	Min.	Typ.	Max.	Unit
Reverse Breakdown Voltage at $I_R = 100 \mu A$	$V_{(BR)R}$	32	–	–	V
Leakage Current at $V_R = 30 V$	I_R	–	–	10	nA
Capacitance $f = 1 MHz$ at $V_R = 28 V$ at $V_R = 1 V$	C_{tot} C_{tot}	2.4 36.0	– –	2.9 42.0	pF pF
Effective Capacitance Ratio, $f = 1 MHz$ at $V_R = 1$ to $28 V$	$\frac{C_{tot}(1 V)}{C_{tot}(28V)}$	13.5	–	–	–
Series Resistance at $f = 470 MHz$, $C_{tot} = 25 pF$	r_s	–	0.80	–	Ω
Series Inductance	L_s	–	2.5	–	nH
For any two of six consecutive diodes in the carrier tape, the maximum capacitance deviation in the reverse bias voltage of $V_R = 0.5$ to $28 V$ is max. 2.5%					

RATINGS AND CHARACTERISTIC CURVES BB729S

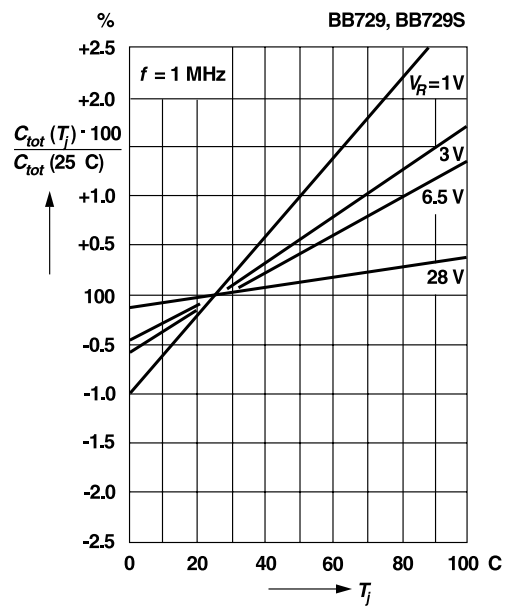
Capacitance
versus reverse voltage



Leakage current
versus reverse voltage



Relative capacitance
versus junction temperature



Q-Factor
versus frequency

